

Hall effect in the marginal Fermi liquid regime of high- T_c superconductors

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The detailed derivation of a theory for transport in quasi-two-dimensional metals, with small-angle elastic scattering and angle-independent inelastic scattering is presented. The transport equation is solved for a model Fermi surface representing a typical cuprate superconductor. Using the small-angle elastic and the inelastic scattering rates deduced from angle-resolved photoemission experiments, good quantitative agreement with the observed anomalous temperature dependence of the Hall angle in optimally doped cuprates is obtained, while the resistivity remains linear in temperature. The theory is also extended to the frequency-dependent complex Hall angle.

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I. INTRODUCTION

Soon after the discovery of high-temperature superconductivity in the cuprate compounds, it was found that all the transport properties for compositions near those for the maximum T_c have anomalous temperature and/or frequency dependence, in contrast to what is expected for Landau Fermi liquids. Most of the anomalies, in resistivity and optical conductivity, in the frequency dependence of Raman intensity, in the tunneling spectra, and in the temperature dependence of the copper nuclear relaxation could be understood by the "Marginal Fermi Liquid" (MFL) phenomenology.¹ Within MFL, scale-invariant fluctuations in both in the charge and magnetic sectors are assumed to have the form,

$$\begin{aligned} \text{Im}(\chi(\mathbf{q}; \omega; T)) &= N_0(\omega = T); \quad \omega \ll T \\ &= N_0(\text{sgn}(\omega)); \quad T \ll \omega \ll \omega_c; \end{aligned} \quad (1)$$

characteristic of a quantum critical point. ω is the frequency and \mathbf{q} the momentum of the fluctuations, N_0 is the density of energy states per unit volume and ω_c is a high-frequency cutoff. At long wavelengths this form is observed directly in Raman scattering². A principal prediction¹ from this hypothesis is that at low energies ($\omega \ll T$), the inelastic part of the single-particle relaxation rate has the MFL form $\propto T$ with coefficient having negligible momentum dependence either along or perpendicular to the Fermi surface. This form has been confirmed in angle-resolved photoemission (ARPES) experiments³ and leads directly to the observed linear temperature dependence of the resistivity.

However, the temperature dependence of anomalies in the normal state Hall effect and magnetoresistance could not be understood by the MFL hypothesis alone. For example, for a situation near optimal doping, where the resistivity is linear in temperature, the expectation is that the cotangent of the Hall angle ($\cot \theta_H = \rho_{xy}/\rho_{xx}$) should also be linear. Experiment shows it to be more nearly quadratic. This left open the possibility that essential new physics

near optimal doping may not be captured by the MFL scenario. In this paper we show that the temperature dependence of the Hall angle may be understood quantitatively by a proper application of transport theory using the measured single-particle relaxation rates.

The single-particle self energy $\Sigma(\mathbf{k}; \omega; T)$ is measurable in angle-resolved photoemission (ARPES) experiments.^{3,4} As stated above, within MFL, the prediction is that the inelastic part of Σ is \mathbf{k} -independent and of the MFL form,¹ proportional to ω for $\omega \ll T$ and to T for $T \ll \omega$. ARPES experiments³ do find the inelastic part of this form but find in addition an elastic part which varies in magnitude around the Fermi surface. Thus, as explained in detail earlier,⁴ on the Fermi surface ($\omega = 0$), the experimentally-measured self energy consists of the MFL part $\propto T$ and an anisotropic T -independent elastic part:

$$\text{Im}(\Sigma(\mathbf{k}; T)) = T + \hat{\kappa}(\mathbf{k}); \quad (2)$$

According to experiment, $\hat{\kappa}(\mathbf{k})$ increases by about a factor 4 to 5 going from the $(\pi; \pi)$ to the $(\pi; 0)$ direction along the Fermi surface.⁴ A crucial point is that even at its minimum value, it is more than an order of magnitude larger than the transport scattering rate due to impurities obtained by extrapolating the normal state resistivity to $T = 0$. As argued in Ref. 4, such behavior arises if $\hat{\kappa}(\mathbf{k})$ comes from small-angle impurity scattering. We discuss this point further in Sec. V II.

In a previous communication,⁵ we described, for high- T_c superconductors, how Eq. (1) can be used in a Boltzmann equation analysis to account for observed anomalies^{6,7,8,9,10,11} in the Hall effect. We performed a calculation (page 4655 of Ref. 1) using a simple Fermi surface in order to give an example of how a new contribution¹² could dominate the conventional result and thus account for experimental observations. However it was pointed out to us by V. Yakovenko¹³ that we erred in the form we chose to parameterize $\hat{\kappa}(\mathbf{k})$.¹⁴ The purposes of this paper are to give a more complete solution

of the Boltzmann equation, correct the above error, and to present a model calculation which illustrates how, with a proper parameterization and a reasonable choice of parameters, the presence of the anisotropic impurity scattering together with other anisotropies can account for the observed behavior of the Hall angle.^{6,7,8,9,10,11} Further, we generalize our results to the complex Hall angle at finite frequencies which has been recently measured.¹⁵

A point about the experimental results needs stressing. In many presentations of the data, for example Refs. 9,10, single temperature non-integer power-law fits to the Hall number or the Hall angle have been made, with varying success, while integer power law fits⁶ do not usually faithfully represent the data. There is no physical reason to expect integer power law behavior and our analysis shows quite generally that the solution of the Boltzmann equation can give a sum of contributions with different temperature dependences. In particular, it is usually found^{9,10} that a temperature power law with a power less than 2 can fit the data for the cotangent of the Hall angle. As we show here, this is indistinguishable from the ratio of terms each of which is a sum of contributions with different temperature dependences.

Our results have two significant conclusions. First, anisotropies, especially in the scattering rate, introduce corrections to the calculation of magnetotransport properties so that conventional results such as $R_H = (\hbar c)^{-1}$, or $\tan \theta_H = \mu_{\text{tr}}$ are not in general valid.¹⁶ Second, the fact that the Hall effect in the cuprates can be understood within transport theory, with only the measured single-particle relaxation rate, the measured resistivity and Fermi surface quantities as inputs implies that no new physics is involved other than what leads to the behavior of those quantities. We conclude that the MFL, which gives the experimentally observed temperature dependence of the relaxation rate, is sufficient to account for all the anomalous magnetotransport near optimal doping. This point of view is reinforced by recent frequency-dependent complex Hall effect measurements¹⁵ whose results are consistent with the analysis presented here, as discussed in Sec. VI.

II. TRANSPORT EQUATION

At long wavelengths and low frequencies the derivation of Boltzmann equation relies only on conservation laws and is valid whether the system is a Fermi liquid or not. Therefore we start with the linearized Boltzmann equation for the deviation $g(k;t)$ of the momentum distribution function from its equilibrium value $f(k)$ in the presence of uniform static electric and magnetic fields,

$$\frac{\partial g_k}{\partial t} + eE \cdot \nabla_k \frac{\partial f}{\partial k} + \frac{e}{\hbar c} (v_k \cdot B) \times g_k = C_k \quad (3)$$

Here $C(k)$ is the collision operator. The solution to this equation for the stationary case ($\partial/\partial t = 0$) is given by¹⁷

$$g(k) = e\hbar \sum_{k^0} A_{k,k^0}^{-1} E \cdot \nabla_k \frac{\partial f}{\partial k^0}; \quad (4)$$

where

$$A_{k,k^0} = \hbar \frac{1}{(k)} + \frac{e}{\hbar c} v_k \cdot B \times \nabla_k C_{k,k^0}; \quad (5)$$

Here C_{k,k^0} is the "scattering-in" term in the collision operator for the Boltzmann equation and $\hbar/(k) = \sum_{k^0} C_{k,k^0}$, is the "scattering-out" term equal to the single-particle relaxation rate. It is evident that the distribution $g(k)$ is not only determined by the energy of the state k but also by the anisotropy of the scattering. The distribution is depleted in directions of large net scattering and augmented in directions of small net scattering.

We calculate the conductivities using the single-particle scattering rate of Eq. (2). The conductivity tensor is

$$= \frac{e^2 \hbar}{4\pi} \sum_{k,k^0} v_k A_{k,k^0}^{-1} v_{k^0} \frac{\partial f}{\partial k^0}; \quad (6)$$

where π is the sample (taken to be a plane) area. We expand A^{-1} from Eq. (4) in powers of B :¹⁷

$$A^{-1} = T + (\hbar c)^{-1} T (v \cdot B \cdot r) T + (\hbar c)^{-2} T (v \cdot B \cdot r) T (v \cdot B \cdot r) T; \quad (7)$$

where (from Eq. (2.12) of Ref. 17)

$$T_{k,k^0} = \frac{1}{\hbar} \left[\delta_{k,k^0} + \sum_{k^{\infty}} C_{k,k^{\infty}} T_{k^{\infty},k^0} \right] \quad (8)$$

The first term in A^{-1} gives the longitudinal conductivity, the second the Hall conductivity σ^{xy} and the magnetotransport conductivity may be calculated from the third term.

As discussed above, the δ_{k,k^0} is the MFL scattering plus the angle dependent impurity piece:

$$\delta_{k,k^0} = \delta_{k,k^0}^{\text{M}} + \delta_{k,k^0}^{\text{i}}(\hat{k}); \quad (9)$$

Our approach to solving Eq. (7) is to take advantage of the properties of $\delta_{k,k^0}^{\text{M}}$ and $\delta_{k,k^0}^{\text{i}}$. The kernel C in Eq. (8) comprises the vertex corrections for the various scattering mechanisms. Within MFL, the $\delta_{k,k^0}^{\text{M}}$ is an s-wave scattering process so the MFL interaction does not appear in C . That leaves

$$C_{k,k^0} = 2 \sum_{k^{\infty}} (k - k^{\infty}) j_1(\hat{k}; \hat{k}^{\infty}) f_{k^{\infty}}^2; \quad (10)$$

where, e.g., \hat{k} is the angle of \hat{k} along the Fermi surface. We have argued^{4,5} that the impurity scattering matrix element $u_i(\hat{k}; \hat{k}^{\infty})$ involves scattering through small angles only. This property allows an expansion of the RHS of

Eq. (8) in powers of a "small angle scattering parameter", ϵ_c which can itself be a function of θ . We illustrate such an expansion for the calculation of l_{\parallel} :

$$\frac{1}{l_{\parallel}}(\theta) = \frac{1}{h} \sum_{k^0}^X j_{\parallel}(\theta; 0) f^0(\theta) + \frac{3}{24} \frac{d^2}{d\theta^2} U(\theta; 0) N(\theta) \quad (11)$$

Here we have used

$$\sum_k^X = \frac{1}{2} \frac{d}{d\theta} N(\theta) \quad ; \quad N(\theta) = \frac{dk_t = d}{2 \hbar v(\theta)} \quad (12)$$

$N(\theta)$ is the density of states per unit energy at the Fermi surface at angle θ and $v(\theta)$ is the Fermi velocity. dk_t is an infinitesimal taken tangent to the Fermi surface at the angle θ . We have abbreviated $j_{\parallel}(\theta; 0) f^0$ by $U(\theta; 0)$. We shall describe below how experiments show that ϵ_c is indeed sufficiently small to justify such an expansion.

III. LONGITUDINAL CONDUCTIVITY

We begin by determining the longitudinal conductivity within the model. We first give the solution for a general Fermi surface and then specialize to a particular example to illustrate the results.

From Eqs. (5,6), we have

$$\sigma_{xx} = \frac{e^2 \hbar}{4\pi} \sum_{k, k^0}^X v_k^x T_{k, k^0} v_{k^0}^x \left(\frac{\partial f}{\partial \epsilon} \right) \quad (13)$$

Define the vector L as

$$L_k = \sum_{k^0}^X T(k; k^0) \left(\frac{\partial f}{\partial \epsilon} \right) v_{k^0}^x \quad (14)$$

so that

$$\sigma_{xx} = \frac{e^2 \hbar}{4\pi} \sum_k^X v_k^x L_k^x \quad (15)$$

Using Eq. (8) in Eq. (14), we find the integral equation for L :

$$L_k = \frac{k}{h} \left(\frac{\partial f}{\partial \epsilon} \right) v_k^x + \sum_{k^0}^X C_{k, k^0} L_{k^0} \quad (16)$$

As discussed earlier, C contains only the small angle scattering so that

$$L_k = \frac{k}{h} \left(\frac{\partial f}{\partial \epsilon} \right) v_k^x + \frac{1}{d} \int_0^{\theta} N(\theta') U(\theta; \theta') L_{k^0} \quad (17)$$

which, since L is restricted to the Fermi surface, can be rewritten as

$$\frac{h}{l_{\parallel}}(\theta) = \left(\frac{\partial f}{\partial \epsilon} \right) v(\theta) + \frac{h}{l_{\parallel}}(\theta) + \frac{1}{d} \int_0^{\theta} N(\theta') U(\theta; \theta') [L(\theta') - L(\theta)] \quad (18)$$

where $l_{\parallel} = l_{\parallel} = l_{\parallel} = l_{\parallel}$ is given in Eq. (11). Given the small angle scattering restriction on $U(\theta; \theta')$, we expand the difference $L(\theta') - L(\theta)$ and find the differential equation (primes indicate derivatives with respect to θ)

$$M(\theta) = v(\theta) + u(\theta) M'(\theta) + 2u'(\theta) M(\theta) \quad (19)$$

where

$$M(\theta) = \frac{h}{M(\theta) \left(\frac{\partial f}{\partial \epsilon} \right)} L(\theta) \quad (20)$$

and

$$u(\theta) = \left(\frac{3}{4} \right) \left(\frac{1}{M} \right) N(\theta) U(\theta; \theta); \quad u'(\theta) = \left(\frac{3}{4} \right) \left(\frac{1}{M} \right) \left[\frac{d}{d\theta} N(\theta) U(\theta; \theta) \right] \quad (21)$$

This differential equation can be solved for the components of M , hence L , once the θ -dependences of v ; u and u' are known. This equation, which is basic to the evaluation of both the longitudinal and the Hall conductivities is completely equivalent to Eq. (10) of Ref. 5. Although u contains a small parameter an iterative solution of Eq. (19), as in our previous work,⁵ is not valid. We solve Eq. (19) exactly in this paper.

As we discussed previously,^{5,14} the details of the anisotropies of the quantities entering the transport coefficients determine the magnitudes of the various contributions, in particular to σ_{xy} in the presence of a magnetic field. The shape of the Fermi surface is especially important since it determines the size of the contribution to σ_{xy} from the isotropic marginal Fermi liquid scattering rate $l_{\parallel} = l_{\parallel}$. In what follows, we take the anisotropy of the impurity scattering from ARPES data and we assume a simple form for the Fermi surface velocity.

A schematic of the Fermi surface is shown in Fig. 1, where the angular variable θ is shown. A general Fermi surface respecting the square symmetry of the CuO_2 layers must have Fermi velocities in the first quadrant of the form

$$v_x = \sum_n^X v_n \sin[(2n+1)\theta] \quad v_y = \sum_n^X v_n (1)^n \cos[(2n+1)\theta] \quad (22)$$

For our calculations we take a form for $v(\theta)$ which is the simplest extension beyond the circular Fermi surface (similar to that shown in Fig. 1) consistent with Eq. (22). In the first quadrant,

$$v_x = v_0 (\sin \theta + \sin 3\theta) \quad v_y = v_0 (\cos \theta - \cos 3\theta) \quad (23)$$

For this choice for $v(\theta)$, the density of states of Eq. (12) in all quadrants is

$$N(\theta) = \frac{k_0}{2 \hbar v_0} \frac{(1 - \cos 4\theta)^{3/4}}{(1 - \cos 4\theta)^{3/4}} \quad (24)$$

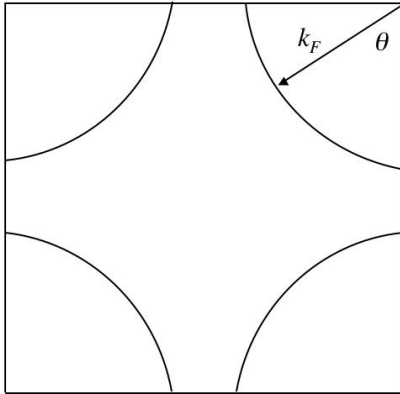


FIG. 1: Schematic Fermi surface.

where k_0 is the value of $k_F(\theta)$ at $\theta = 0$.

Thus, according to Eq. (15), ρ_{xx} is given by:

$$\rho_{xx} = \frac{e^2 M}{2h} \left(\frac{1}{\cos^4 \theta} \right)^{j=4} \frac{k_0^2}{v_0} \int_0^{2\pi} d\theta \frac{v_x(\theta) M_x(\theta)}{(1 - \cos^4 \theta)^{j=4}}; \quad (25)$$

IV. HALL CONDUCTIVITY

For a magnetic field perpendicular to the xy plane, $\mathbf{v} \times \mathbf{B} = \frac{1}{2} \hbar N(\theta) \mathbf{B}$ at $\theta = \theta$ and from Eqs. (6,7),

$$\rho_{xy} = \frac{e^2 B}{2c} \sum_{\mathbf{k}, k_0, k_1}^X v_k^x \frac{T(\mathbf{k}; k_1)}{N(\theta_1)} \frac{dT(\mathbf{k}_1; k_0)}{d\theta_1} \left(\frac{\partial f}{\partial \epsilon} \right) v_{k_0}^y; \quad (26)$$

We rewrite this using Eq. (14):

$$\rho_{xy} = \frac{e^2 B}{2c} \sum_{\mathbf{k}, k_1}^X v_k^x \frac{T(\mathbf{k}; k_1)}{N(\theta_1)} \frac{d}{d\theta_1} L_{k_1}^y; \quad (27)$$

We define

$$K_k = \sum_{k_0}^X T(\mathbf{k}; k_0) \frac{1}{N(\theta_0)} \frac{d}{d\theta_0} L_{k_0}; \quad (28)$$

so that

$$\rho_{xy} = \frac{e^2 B}{2c} \sum_{\mathbf{k}}^X v_k^x K_k^y; \quad (29)$$

Using Eq. (16) in Eq. (31), we get an integral equation for K :

$$K_k = \frac{k}{h} \left(\frac{1}{N(\theta)} L_k^0 + \sum_{k^{00}}^X C_{k, k^{00}} K_{k^{00}} \right)$$

$$= \frac{k}{h} \frac{L_k^0}{N(\theta)} + \int d\theta N(\theta) U(\theta; \theta_0) K(\theta_0); \quad (30)$$

We proceed exactly as in the analysis for L , Eqs. (16-21). For the required K_y , we find the differential equation

$$Z(\theta) = M_y^0(\theta) (1 - \cos^4 \theta)^{j=4} + u(\theta) Z^{00}(\theta) + 2u^0(\theta) Z^0(\theta) \quad (31)$$

where $Z(\theta)$ determines $K_y(\theta)$ as

$$K_y(\theta) = \frac{M}{h} \frac{1}{2} \frac{2}{k_0} \frac{\hbar v_0}{(1 - \cos^4 \theta)^{j=4}} \left(\frac{\partial f}{\partial \epsilon} \right) Z(\theta); \quad (32)$$

and M_y is obtained as the solution of Eq. (19). As in that case, an iterative solution of Eq. (31) is not valid. Combining all our results into Eq. (29), we find

$$\rho_{xy} = \frac{e^3 B}{2c} \frac{M}{h} \int_0^{2\pi} d\theta \frac{1}{(1 - \cos^4 \theta)^{j=4}} v_x(\theta) Z(\theta) \quad (33)$$

When there is no small-angle scattering, $M_y = v_y$ and $Z(\theta) = \frac{1}{3} (\sin^3 \theta - \sin^3 \theta_0) (1 - \cos^4 \theta)^{j=4}$. In that case,

$$\rho_{xy} / \int_0^{2\pi} d\theta (\sin^2 \theta - \sin^2 \theta_0) \quad (34)$$

which vanishes when $\theta_0 = 1 = \frac{\pi}{3}$. This is the familiar result of the vanishing of ρ_{xy} when the Fermi surface consists of equal portions of positive and negative curvature. One sees that the anisotropic small-angle contributions, which have a leading contribution proportional to $\frac{1}{M^3}$, i.e. to $1/T^3$, do not vanish there.

V. CHOICE OF PARAMETERS AND COMPARISON WITH EXPERIMENTS

We now describe the evaluation of the conductivities using experimental data from ARPES and from the longitudinal transport in zero magnetic field. The strategy is as follows. The anisotropies in the problem will be determined from the anisotropy of the impurity scattering $1/\tau_i(\theta) = 2/\hbar$ as determined from ARPES. For simplicity, we shall let the density of states $N(\theta)$ be responsible for the anisotropy of $1/\tau_i$, and hence for the quantity $u(\theta)$, see Eq. (21). The measured anisotropy of $1/\tau_i$ from the θ direction to the θ_0 direction in the Brillouin zone then determines the velocity anisotropy parameter from Eqs. (11,24). These parameterizations give the correct behavior at the edges of the Brillouin zone. The small angle parameter c can then be found from the "residual resistance" ratio (RR) of the resistivity at T_c to the extrapolated value at $T = 0$. That is sufficient to determine the T -dependence of $\cot \theta_H = \rho_{xx} = \rho_{xy}$. The magnitude of $\cot \theta_H$ is then fixed by the effective mass $\hbar k_0 = v_0$, which we leave as an adjustable parameter. It will be seen that the effective mass has a quite reasonable value.

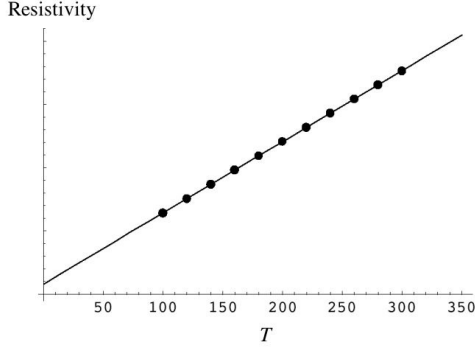


FIG. 2: Linear temperature ρ to calculated resistivity (dots) from Eq. (33) for $T_c = 24 = 0.0014$. The resistance ratio, $\rho(100) = \rho(0)$, is 8.

The conductivities are given by Eqs. (25,33). The quantity u which appears in the differential equations for M and Z is defined as $u(\theta; T) = (\frac{2}{c} = 24) M = i(\theta) = (M = h)(\frac{2}{c} = 24) N(\theta) U(\theta; T)$. The measured anisotropy of $\hat{k} = h = 2$ is about 4.5. We assign this to $N(\theta)$, thus determining U from Eq. (24) as $U = 0.54$. Therefore, we have

$$\begin{aligned} l = i(\theta) &= (l = 0)(1 - \cos 4\theta)^{5/4}; \\ u(\theta; T) &= u_0(T)(1 - \cos 4\theta)^{5/4}; \\ &= 0.54: \end{aligned} \quad (35)$$

The quantity $u_0(T) = M(T)(\frac{2}{c} = 24) = 0$. $M(T)$ and 0 may be determined from ARPES as described in Ref. 3. From ARPES, $h = i = 0.24$ eV at $T = 8$. So $h = 0 = 0.24$ eV. From the same source, $h = M = 0.015$ (T=100) eV, where T is in Kelvin. This determines u_0 as $u_0(T) = 16(100=T)(\frac{2}{c} = 24)$. The remaining parameter u_0 , that is c , is determined from the resistance ratio RR as follows.

The longitudinal resistivity in zero magnetic field ρ_{xx} is given by the inverse of σ_{xx} from Eq. (25). Unfortunately we do not have an analytic solution of the differential equation Eq. (19) for M_x , although the coefficients are now known from Eq. (35). Numerical integrations of Eqs. (19,25) are performed for different values of $u_0(T) = (1600=T)(\frac{2}{c} = 24)$. For a given value of c , ρ_{xx} is almost precisely linear in T above $T = 100$ K. See Fig. 2. The $T = 0$ intercept of ρ_{xx} , ρ_0 , is obtained by extrapolating the found high temperature linear dependence. The RR is defined as $\rho_{xx}(T = 100) = \rho_0$, and is typically about 8, say. This is obtained for $u_0(T) = 0.22(100=T)$ so that the characteristic small angle parameter is indeed small, $\frac{2}{c} = 24 = 0.0014$.

All parameters are now fixed with the exception of $m = h k_0 = v_0$. The numerical integrations of Eqs. (19,31,33) for M_y ; Z and σ_{xy} respectively can be carried out for different values of T and combined with the previ-

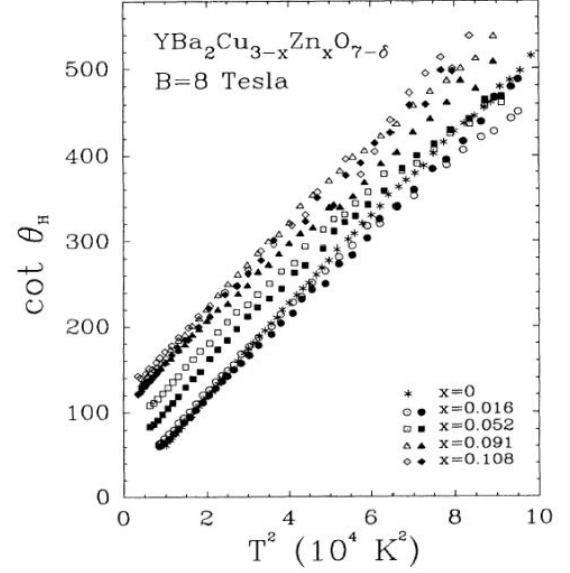


FIG. 3: Data of Chien, et al, Phys. Rev. Lett. 67, 2088 (1991).

ous result for $\rho_{xx}(T)$ to give $\cot \theta_H(T) = \rho_{xx}(T) = \rho_{xy}(T)$:

$$\cot \theta_H(T) = \frac{0.82}{!_c M} \frac{m}{m} \frac{R \frac{dn(\theta)}{d\theta} (M_x(\theta))}{\frac{dn(\theta)}{d\theta} (Z(\theta))}; \quad (36)$$

where we have used $U = 0.54$, $!_c$ is the cyclotron frequency with the bare mass and $n(\theta) = (1 - 0.54 \cos 4\theta)^{5/4}$.

We now compare our result with the experiment of Chien, et al.⁶ They measured the Hall angle as a function of temperature for various concentrations of Zn in purities in near-optimally doped YBCO. Their data at $B = 8$ T ($!_c = 1.28 \times 10^{12} \text{ s}^{-1}$) is reproduced in Fig. 3.

We examine the data for zero Zn concentration. In Fig. 4, we have replotted the $x = 0$ points from Fig. 3 (large dots) and the theoretical result (small dots) of Eq. (36) with $m = m = 1.5$, so adjusted to give the best agreement. It is important that m turns out to be reasonable. We emphasize that the parameters we picked were determined from ARPES experiments on BiSCO, while the Hall data is on YBCO. Thus, our intent here is only to show that the scattering rates characteristic of high- T_c superconductors in the normal state near optimal doping can by themselves account for the temperature dependence of the Hall angle, not to demonstrate quantitative agreement with a particular experiment. It is seen that the experimental temperature dependence is fairly well reproduced.

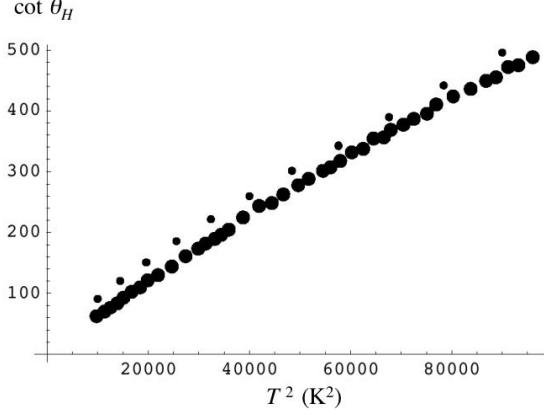


FIG. 4: Theory $\cot \theta_H$ to $x = 0$ data of Chien, et al.⁶

Notice that the experimental curves have a negative curvature on a T^2 plot. While this might suggest a power law less than 2 and several investigators have tried such a fit,^{9,10} our picture indicates that this behavior is a consequence of the fact that the conductivities are each the sum of two terms with approximate $1/T^n$ and $1/T^{n+1}$ (xx : $n = 1$; xy : $n = 2$) dependences.

The data of Ref. 6 and our theory both suggest that in the absence of in-plane impurities such as Zn, the extrapolated $\cot \theta_H$ at $T \rightarrow 0$ is zero. In-plane impurities will in general not give scattering restricted to small angles. Indeed, their influence is evident in the measured resistivity. We could include their effects by assuming them to be isotropic scatterers which add a constant $1/\tau_z$ to the isotropic linear in temperature MFL rate $1/\tau_M$. This has the effect of an almost parallel upward shift of $\cot \theta_H$ so that it has a zero temperature intercept proportional to $1/\tau_z$, i.e. to the in-plane impurity concentration. We illustrate this qualitatively using some data from Ref. 9. In Fig. 5, we show the data (large dots) for $B_{1-x}Sr_xLa_xCuO_6$ with $x = 0.44$ (optimal doping). It is seen that the data does not extrapolate with a zero intercept. We interpret this as signalling the presence of in-plane scatterers. The theoretical curve (small dots) uses similar parameters as in Fig. 4 but with an in-plane impurity contribution added to $1/\tau_M$.

VI. COMPLEX HALL CONDUCTIVITY

In this section, we comment on the recent ac Hall effect results of Grayson, et al.¹⁵ For low frequencies and $T > T_c$, we can replace $1/\tau_M \rightarrow 1/\tau_{tr}$ by $1/\tau_{tr} - i!$. This follows immediately from Eqs. (3-5): the distribution function $g(k; !)$ and therefore the transport properties are obtained from the $! = 0$ results by this replacement.

From Fig. 2 it is seen that the resistivity is almost precisely linear in T in the normal state: $^{xx} = a + bT$, where a is the (small) residual resistivity due to the small-

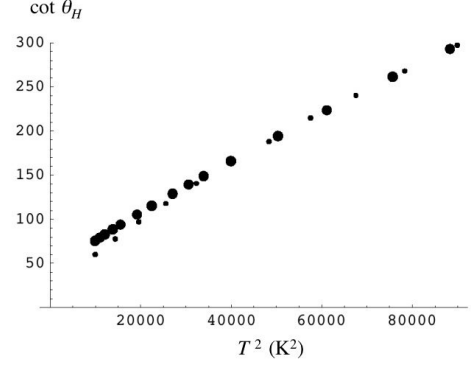


FIG. 5: Comparison of theory (small dots) including in-plane scatterers with data (large dots) from Ref. 9, for optimally doped BSLCO.

angle impurity scattering. Thus, $a=b$ is about 10, say. We have also found that $^{xy}(T)$ is, in the temperature range of interest, very closely of the form $cT^2 + dT^3$, with $c=d \approx 0.01 K^{-1}$. Therefore, neglecting quantities of order 0.1, our prediction for the Hall angle is

$$\tan \theta_H(!; T) = \frac{^{xy}}{^{xx}} = A \frac{1}{(1/\tau_{tr} - i!)^2} + \frac{c}{d} \frac{1}{(1/\tau_{tr} - i!)} \quad (37)$$

where A and $c=d$ are constant in temperature. The latter ratio is now in units of seconds; for our example parameters it is about 2×10^{14} s. We emphasize that a single relaxation rate $1/\tau_{tr}$ enters all our expressions. The constant A in Eq. (37) corresponds to the quantity $!_{H-p}$ of Ref. 15. In that reference, Fig. 4 shows that A is indeed temperature and frequency independent. The $c=d$ term is the conventional term. In Ref. 15, it was shown that by itself it cannot account for the experimental data. Just as the dc data shows deviations from T^2 behavior for $\cot \theta_H$, we expect that the ac data should be fit by a combination of the two terms in Eq. (37). At higher frequencies or temperatures, the conventional term should naturally dominate. The complex Hall angle measurements convincingly demonstrate that just one inelastic transport rate determines all the frequency and temperature dependence of the transport properties of the high- T_c superconductors in the marginal Fermi liquid region, i.e. in their normal state near optimal doping.

When calculating the ac conductivity, the limits of applicability of the Boltzmann equation should be kept in mind. The results are only valid for $! \ll 1$. In this regime the conservation laws (in terms of bare particles) completely determine transport and the Boltzmann equation deals with them properly. In a microscopic theory, the effects of small-angle scattering calculated here appear as corrections to the coupling of the external magnetic field to the carriers. At high enough frequency these vertex corrections must vanish. The crossover frequency and the behavior of transport properties in the interme-

diate regime can only be determined by a microscopic calculation. Experimental results at high frequencies do depart from the predictions of Eq. (37).

V II. CONCLUDING REMARKS

Here we discuss sundry issues related to the theory and calculations presented in this paper. We emphasize that this work pertains only to the Hall effect in optimally or overdoped samples. For the latter, the linear-in-temperature scattering rate $1/\tau_M$ should be replaced in the theory by a rate with the T -dependence of the observed resistivity. In underdoped cuprates, additional physical considerations appear to determine the transport and equilibrium properties.

A . Magnetoresistance

Earlier,⁵ we gave a plausibility argument that the observed magnetoresistance would follow quantitatively from the same considerations which lead to the observed Hall effect. We leave it as a future exercise to calculate this quantity directly from the solution of the Boltzmann equation as an extension of the present theory.

B . Small-angle scattering, Fermi surface geometry, bilayer splitting ...

We have modeled the Fermi velocity through Eq. (23), which with $\gamma = 0.54$ is in itself enough to give the observed angular variation of the elastic part of the single-particle relaxation rate. As we have seen, this also gives agreement with the observed temperature dependence of the Hall angle. This value of γ is 10% away from the value at which the customary Hall coefficient would be zero. This seems to us reasonable, since in a model with nearest neighbor Cu-O hopping alone, the Hall effect is zero at half-filling and with O-O hopping included, the density for zero Hall effect shifts substantially towards hole doping. The optimal doping composition lies in the range 15–20% hole doping. In this connection, it is important to remember that we are using parameters obtained from experiments on BSCCO to fit Hall data on YBCO. Therefore the precise numbers are not too meaningful; we only argue that we have shown that the small-angle scattering scenario gives the qualitative features of the experiments.

In our numerical analysis, we have chosen the simplest parameterization of the Fermi velocity to show the plausibility of the small-angle effect in relation to the experiments. Our parameterization should not be expected to represent the Fermi surface adequately. For the actual Fermi surface several terms in Eq. (22) for the Fermi velocity would have to be included with coefficients smaller than γ . We note however that the successive terms give

compensatingly larger coefficients since the higher harmonics produce larger derivative terms in Eq. (36) for v_{xy} . For a truer Fermi surface the advantage of analytical calculations is lost. These remarks are of academic interest at the present time since the actual Fermi surface is not accurately known.

More relevant is the fact that the Fermi surface of Bi-2212, the ARPES data for which we have used here, has two sheets coming from the bilayer splitting. The bilayer splitting varies as a function of angle, being largest in the $\pi/2$ direction. This arises because of the geometry of the interlayer orbitals.¹⁸ This angular variation is essentially the same as that of the observed anisotropic elastic scattering. The fact that the bilayer splitting is not resolved in the experimental data we have used indicates the presence of an elastic scattering mechanism which couples the layers. We surmise that for interlayer or intralayer scattering due to impurities between the planes, the same orbitals are involved and therefore the same angular dependence arises in scattering. In a single-layer model as treated here, this effect is parameterized through the choice of the angle-dependence of the Fermi velocity as in Eq. (23).

C . Comments on related work

As already remarked, although the analytical expressions derived in our earlier work⁵ are correct, we erred, as pointed out by V. Yakovenko, in our choice of the parameterization in which they were evaluated. This error has been remedied here. Our more complete analysis with a simpler parameterization in fact gives results consistent with experiment. We have shown that not only do we get the right temperature dependence but that with a reasonable estimate, the absolute value of the cotangent of the Hall angle is obtained within 10% of the data from the same parameterization.

In Ref. 19, R. Hlubina argues that the new term discovered by us, if adequate to explain the Hall angle, would make an unacceptable contribution to the longitudinal resistivity. Since our parameters are actually determined by the measured resistivity, this criticism is invalid. It is difficult to make a direct comparison with the calculations of Ref. 19 since a quite different parameterization of the Fermi surface is used there. However, we can note that the parameterization family used in Hlubina's evaluation does not include ours and gives a much larger conventional contribution to ρ_{xx} than the one we have used.

A recent paper of Carter and Schoeld²⁰ addresses the main point of our original paper.⁵ Their work consists of two parts. One is analytical, the other is a numerical solution of equations we derived in Ref. 5. We cannot comment on the adequacy of the numerical work, but Carter and Schoeld are indeed correct that the customary term (with a different temperature dependence than the new term) is zero only for a particular choice of Fermi surface.

This is of course well-known: the traditional Hall angle is zero only for "particle-hole symmetry" defined in terms of the curvature of the Fermi surface. However, as we have shown here, it is not necessary that the customary term be zero (and all the temperature dependence come from our new term) to get good agreement with experiment. It is sufficient that the customary term is about a factor of four smaller than the new term at $T = 100\text{K}$. In fact, the experimental data for $\cot \theta_H$, when plotted against T^2 , usually shows a slight downward curvature. This point has been discussed in Sec. I and is adequately demonstrated in the experimental data shown in Fig. 3-5.

The analytical calculation of Ref. 20, expressed in their Eqs. (7-10), is not sufficiently general to contain the anisotropies required to show the effect we have derived. Their calculation for χ_{xy} is equivalent to retaining only the impurity scattering contribution to the conventional

term, not the new contribution which we have derived. See footnote 22 of Ref. 20 for a comment on this. Actually, the analytical calculation of Ref. 20 is based on a circular Fermi surface and we agree that such a parameterization never leads to a large enough effect.

VIII. ACKNOWLEDGMENTS

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